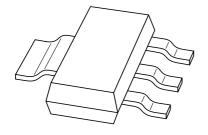
DISCRETE SEMICONDUCTORS

DATA SHEET



BZV90 seriesVoltage regulator diodes

Product data sheet Supersedes data of 1996 Oct 25 1999 May 17



Voltage regulator diodes

BZV90 series

FEATURES

- Total power dissipation: max. 1500 mW
- Tolerance series: approx. ±5%
- Working voltage range: nom. 2.4 to 75 V (E24 range)
- Non-repetitive peak reverse power dissipation: max. 40 W.

APPLICATIONS

• General regulation functions.

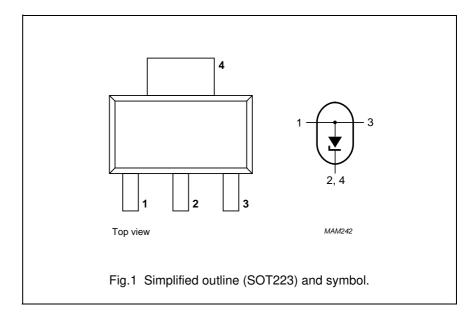
DESCRIPTION

Medium-power voltage regulator diodes in SOT223 plastic SMD packages.

The diodes are available in the normalized E24 approx. $\pm 5\%$ tolerance range. The series consists of 37 types with nominal working voltages from 2.4 to 75 V (BZV90-C2V4 to C75).

PINNING

| PIN | DESCRIPTION |
|------|-------------|
| 1 | anode |
| 2, 4 | cathode |
| 3 | anode |



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-----------------------------------------------|-------------------------------------------------------------------------|-------------------------|------|------|
| I _F | continuous forward current | | _ | 400 | mA |
| I _{ZSM} | non-repetitive peak reverse current | t_p = 100 μs; square wave; T_j = 25 °C prior to surge | see Table "Per type" | | |
| P _{tot} | total power dissipation | T _{amb} = 25 °C; note 1 | _ | 1500 | mW |
| P _{ZSM} | non-repetitive peak reverse power dissipation | t_p = 100 μs; square wave; T_j = 25 °C prior to surge; see Fig.2 | _ | 40 | W |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| T _j | junction temperature | | _ | 150 | °C |

Note

1. Device mounted on an FR4 double-sided copper-clad printed circuit-board; copper area = 2 cm².

ELECTRICAL CHARACTERISTICS

Total series

 $T_i = 25$ °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|----------------|-----------------|-----------------------------------|------|------|------|
| V _F | forward voltage | I _F = 50 mA; see Fig.3 | _ | 1.0 | V |

2

Per type

 $T_i = 25$ °C unless otherwise specified.

Product data sheet

Voltage regulator diodes

DIODE CAP. **TEST REVERSE WORKING DIFFERENTIAL** TEMP. COEFF. NON-REPETITIVE PEAK **CURRENT VOLTAGE RESISTANCE** $S_Z (mV/K)$ C_d (pF) **CURRENT** at **REVERSE CURRENT** $V_{Z}(V)$ $r_{dif}(\Omega)$ at Iztest I_{Ztest} (mA) at f = 1 MHz; **REVERSE** I_{ZSM} (A) **BZV90**see Figs 4 and 5 at $V_R = 0 V$ **VOLTAGE** at $t_p = 100 \mu s$; at Iztest at Iztest CXXX T_{amb} = 25 °C **I**_R (μ**A**) V_{R} (V) MIN. TYP. MAX. MIN. MAX. TYP. MAX. MAX. MAX. MAX. 2V4 2.2 2.6 70 100 -3.5-1.60 5 450 50 1.0 6.0 2V7 2.5 2.9 75 100 -3.5-2.00 5 450 20 1.0 6.0 -2.13V0 2.8 3.2 80 95 -3.50 5 450 10 1.0 6.0 -2.43V3 3.1 3.5 85 95 -3.50 5 450 5 1.0 6.0 -2.4 5 5 3V6 3.4 3.8 85 90 -3.50 450 1.0 6.0 -2.5 3V9 5 3 3.7 4.1 85 90 -3.50 450 1.0 6.0 5 3 4V3 4.0 4.6 80 90 -3.5-2.50 450 1.0 6.0 4V7 4.4 5.0 50 80 -3.5-1.40.2 5 300 3 2.0 6.0 2 2.0 5V1 4.8 5.4 40 60 -2.7-0.81.2 5 300 6.0 5.2 5V6 6.0 15 40 -2.01.2 2.5 5 300 1 2.0 6.0 6V2 5.8 6.6 6 2.3 3.7 5 200 3 4.0 6.0 10 0.4 6V8 6.4 7.2 6 1.2 3.0 4.5 5 200 2 4.0 6.0 15 7V5 5 1 7.0 7.9 6 2.5 4.0 5.3 150 5.0 4.0 15 7.7 8.7 6.2 5 150 0.7 4.0 8V2 6 15 3.2 4.6 5.0 9V1 8.5 9.6 6 15 5.5 7.0 5 150 0.5 6.0 3.0 3.8 5 0.2 7.0 10 9.4 10.6 8 20 4.5 6.4 8.0 90 3.0 11 10.4 11.6 10 20 5.4 7.4 9.0 5 85 0.1 8.0 2.5 12 5 11.4 12.7 10 25 6.0 8.4 10.0 85 0.1 8.0 2.5 13 12.4 14.1 10 30 7.0 9.4 11.0 5 80 0.1 8.0 2.5 15 75 5 2.0 13.8 15.6 10 30 9.2 11.4 13.0 0.05 10.5 16 75 15.3 17.1 10 40 10.4 12.4 14.0 5 0.05 11.2 1.5 18 16.8 19.1 14.4 16.0 5 70 0.05 12.6 1.5 10 45 12.4 20 60 1.5 5 18.8 21.2 15 55 14.4 16.4 18.0 0.05 14.0

Product data sheet

| BZV90- CXXX | VOL ^T | | | - ` ' | | TEST CURRENT I _{Ztest} (mA) | DIODE CAP. C_d (pF) at f = 1 MHz; at V_R = 0 V | REVERSE CURRENT at REVERSE VOLTAGE | | NON-REPETITIVE PEAK REVERSE CURRENT I_{ZSM} (A) at $t_p = 100 \ \mu s$; | | |
|----------------|------------------|------|------|-------|------|--------------------------------------------|----------------------------------------------------|---------------------------------------------|------|----------------------------------------------------------------------------|----------------|--------------------------|
| | | | | | | | | | | I _R (μ A) | V _R | T _{amb} = 25 °C |
| | MIN. | MAX. | TYP. | MAX. | MIN. | TYP. | MAX. | | MAX. | MAX. | (V) | MAX. |
| 22 | 20.8 | 23.3 | 20 | 55 | 16.4 | 18.4 | 20.0 | 5 | 60 | 0.05 | 15.4 | 1.25 |
| 24 | 22.8 | 25.6 | 25 | 70 | 18.4 | 20.4 | 22.0 | 5 | 55 | 0.05 | 16.8 | 1.25 |
| 27 | 25.0 | 28.9 | 25 | 80 | 21.4 | 23.4 | 25.3 | 2 | 50 | 0.05 | 18.9 | 1.0 |
| 30 | 28.0 | 32.0 | 30 | 80 | 24.4 | 26.6 | 29.4 | 2 | 50 | 0.05 | 21.0 | 1.0 |
| 33 | 31.0 | 35.0 | 35 | 80 | 27.4 | 29.7 | 33.4 | 2 | 45 | 0.05 | 23.1 | 0.9 |
| 36 | 34.0 | 38.0 | 35 | 90 | 30.4 | 33.0 | 37.4 | 2 | 45 | 0.05 | 25.2 | 0.8 |
| 39 | 37.0 | 41.0 | 40 | 130 | 33.4 | 36.4 | 41.2 | 2 | 45 | 0.05 | 27.3 | 0.7 |
| 43 | 40.0 | 46.0 | 45 | 150 | 37.6 | 41.2 | 46.6 | 2 | 40 | 0.05 | 30.1 | 0.6 |
| 47 | 44.0 | 50.0 | 50 | 170 | 42.0 | 46.1 | 51.8 | 2 | 40 | 0.05 | 32.9 | 0.5 |
| 51 | 48.0 | 54.0 | 60 | 180 | 46.6 | 51.0 | 57.2 | 2 | 40 | 0.05 | 35.7 | 0.4 |
| 56 | 52.0 | 60.0 | 70 | 200 | 52.2 | 57.0 | 63.8 | 2 | 40 | 0.05 | 39.2 | 0.3 |
| 62 | 58.0 | 66.0 | 80 | 215 | 58.8 | 64.4 | 71.6 | 2 | 35 | 0.05 | 43.4 | 0.3 |
| 68 | 64.0 | 72.0 | 90 | 240 | 65.6 | 71.7 | 79.8 | 2 | 35 | 0.05 | 47.6 | 0.25 |
| 75 | 70.0 | 79.0 | 95 | 255 | 73.4 | 80.2 | 88.6 | 2 | 35 | 0.05 | 52.5 | 0.2 |

Voltage regulator diodes

BZV90 series

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------------|---------------------------------------------|--------------------------|-------|------|
| R _{th j-a} | thermal resistance from junction to ambient | lead length max.; note 1 | 83.3 | K/W |

Note

1. Device mounted on an FR4 double-sided copper-clad printed circuit-board; copper area = 2 cm².

GRAPHICAL DATA

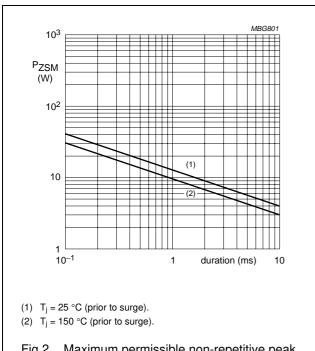


Fig.2 Maximum permissible non-repetitive peak reverse power dissipation versus duration.

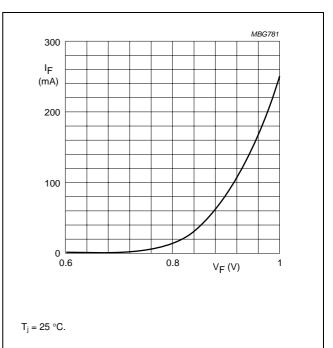
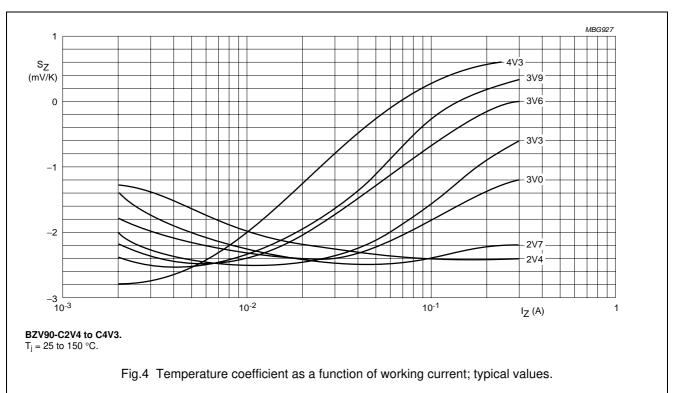


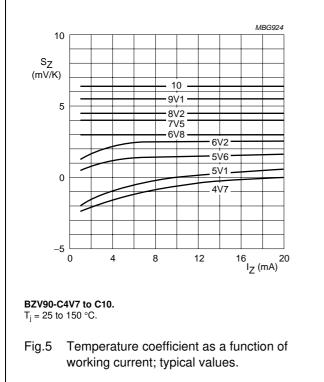
Fig.3 Forward current as a function of forward voltage; typical values.

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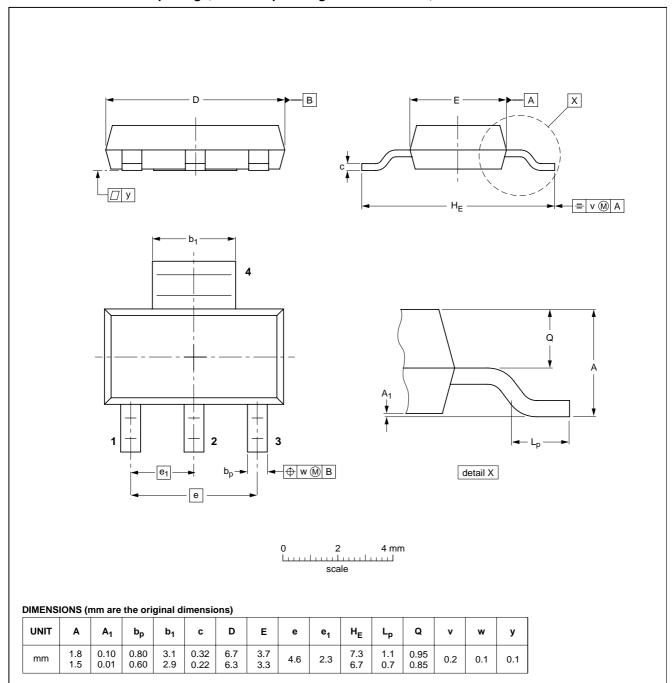
Voltage regulator diodes

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PACKAGE OUTLINE

Plastic surface mounted package; collector pad for good heat transfer; 4 leads

SOT223



| OUTLINE | | REFER | EUROPEAN | ISSUE DATE | | | |
|---------|-----|-------|----------|------------|------------|---------------------------------|--|
| VERSION | IEC | JEDEC | EIAJ | | PROJECTION | ISSUE DATE | |
| SOT223 | | | SC-73 | | | 97-02-28 99-09-13 | |

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DATA SHEET STATUS

| DOCUMENT STATUS(1) | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|------------------------|----------------------------------|---------------------------------------------------------------------------------------|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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